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## Amendments to the claims

1-20. (Canceled)

21. (Previously added and amended) An apparatus for depositing a magnetic film, comprising:

a sputtering chamber containing a target comprising a magnetic sputtering material, a substrate support having a substrate surface that is separated from the target, and a grounded collimator positioned between the target and the substrate support; and

an annular magnet array disposed within the sputtering chamber, the annular magnet array being configured to form a magnetic field that is substantially parallel to the substrate surface of the substrate support, the annular magnet array being concentrically positioned around an outer perimeter of the substrate surface of the substrate support.

- 22. (Previously added) The apparatus of claim 21, wherein the target comprises a material that retains magnetic properties when deposited on the surface of a substrate.
- 23. (Previously added) The apparatus of claim 23, wherein the target is separated from the substrate support by a distance of at least 50 mm.
- 24. (Previously added) The apparatus of claim 21, wherein the annular magnet array comprises a plurality of magnetic segments positioned in an annular configuration around the perimeter of the substrate support, the plurality of magnetic segments having different magnetic orientations that cooperatively combined to magnetic field that is parallel to the substrate surface.
  - 25. (Previously added) The apparatus of claim 23, wherein the target comprises a

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nickel/iron alloy.

26. (Previously added) The apparatus of claim 21 wherein the target and the substrate supporting surface are separated by a distance of at least 50 mm.

27. (Previously added and now amended) A method for depositing a magnetic film within a sputtering chamber containing a target and a substrate, comprising:

sputtering the target onto a surface of the substrate at a pressure less than about 15 mTorr; collimating sputtering of the target with a grounded collimator disposed between the target and the substrate; and

generating a <u>static</u> magnetic field that is substantially parallel to the surface of <u>the</u> substrate during sputtering using <u>an</u> <u>a stationary</u> annular magnet array concentrically disposed around a perimeter of the surface of the substrate within the sputtering chamber.

- 28. (Previously added) The method of claim 27, wherein the sputtering occurs at a chamber pressure less than about 5 mTorr.
- 29. (Previously added) The method of claim 27, wherein the target and the surface of the substrate are maintained at a distance of at least 50 mm during sputtering.
- 30. (Previously added) The method of claim 29, wherein the target comprises a Ni/Fe alloy.
- 31. (Previously added and now amended) The method of claim 27, A method for depositing a magnetic film within a sputtering chamber containing a target and a substrate, comprising:

sputtering the target onto a surface of the substrate at a pressure less than about 15 mTorr;

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collimating sputtering of the target with a grounded collimator disposed between the target and the substrate;

generating a target magnetic field from a magnetron positioned in back of said target with respect to substrate; and

wherein the grounded collimator removes charges from target particles and reduces interference with between the target magnetic field and the parallel static magnetic field which is substantially parallel to the surface of the substrate.

- 32. (Previously added) The apparatus of claim 21, wherein said magnetic field at said substrate surface is substantially parallel to said substrate surface.
- 33. (Previously added) The apparatus of claim 21, wherein said annular magnet array comprises a plurality of permanent magnets.
- 34. (Previously added) The apparatus of claim 33, wherein said plurality of permanent magnets are magnetized parallel to a plane of said substrate surface
- 35. (Previously added) The apparatus of claim 21, wherein said annular magnet array is a Halbach array.
- 36. (Previously added) The method of claim 27 wherein said target comprises a material that is magnetic when sputter deposited in a substantially parallel magnetic field.
- 37. (Previously added) The method of claim 27, wherein said annular magnet array comprises an array of permanent magnets magnetized parallel to a plane of the surface of the substrate during sputtering.

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- 38. (Previously added) The method of claim 27, wherein said annular magnet array comprises a Halbach array.
- 39. (Previously added) The method of claim 27, wherein said magnetic field at the surface of the substrate is substantially parallel to the surface of said substrate.
- 40. (Previously added) The method of claim 27, wherein the substrate is processed to form a magnetic recording head.
- 41. (Previously added) An apparatus for depositing a magnetic film, comprising:
  a sputtering chamber configured to receive a sputtering target for sputter depositing a
  magnetically alignable material onto a substrate supported on a support surface in opposition to
  said target along an axial direction; and

a stationary annular array of permanent magnets surrounding an outer periphery of said support surface and continuously extending from one side to the other side of said support surface parallel to said central axis and creating a magnetic field extending horizontally along said support surface.

- 42. (Previously added) The apparatus of claim 41, wherein said array is a Halbach array.
- 43. (Previously added) The apparatus of claim 40, further comprising a grounded collimator positioned between said target and said support surface.
- 44. (Previously added) The apparatus of claim 40, wherein said material comprises nickel and iron.
  - 45. (New) The apparatus of claim 21, wherein said annular magnet array is stationary and

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producing a static magnetic field.